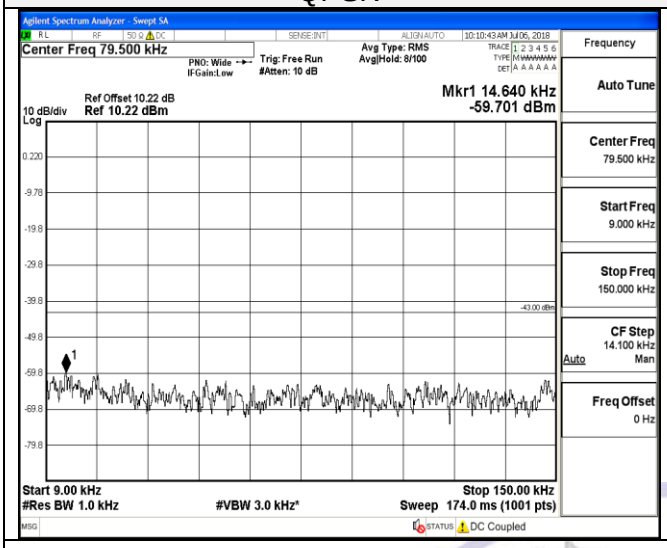
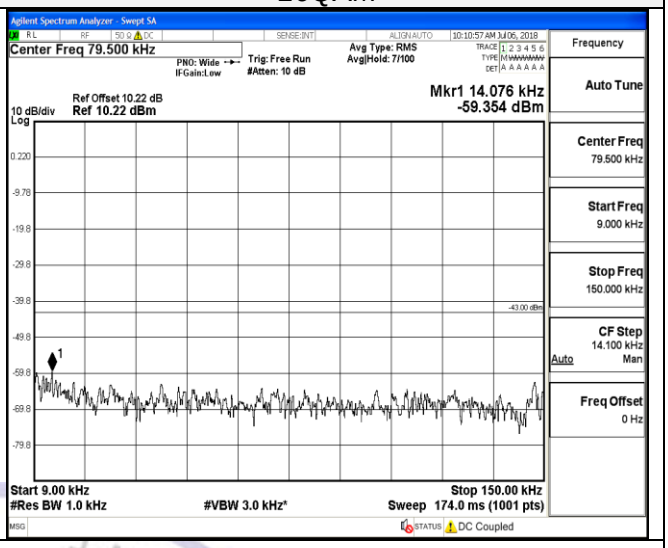
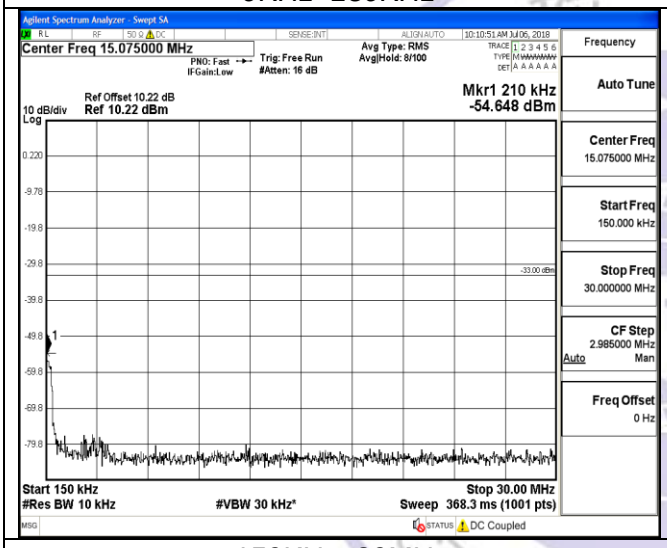
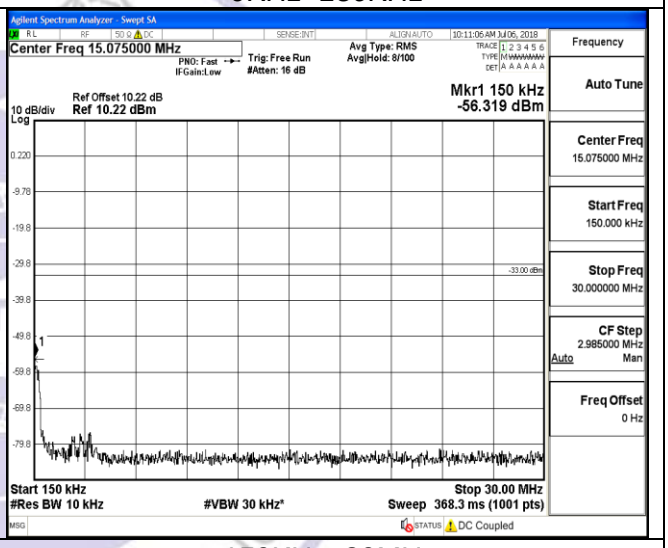
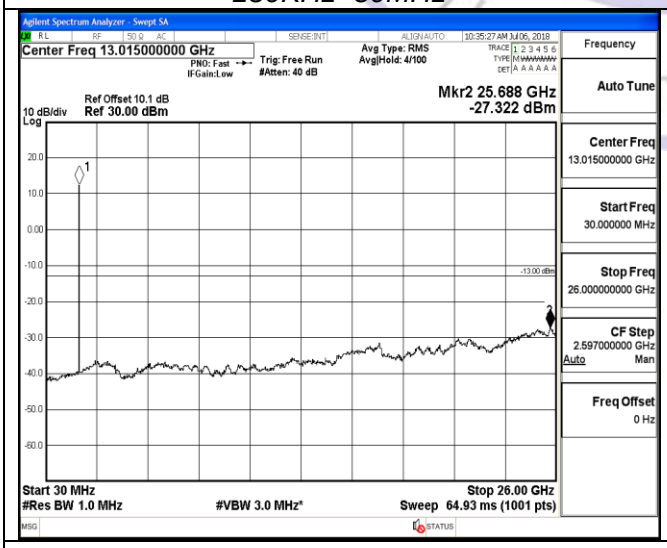
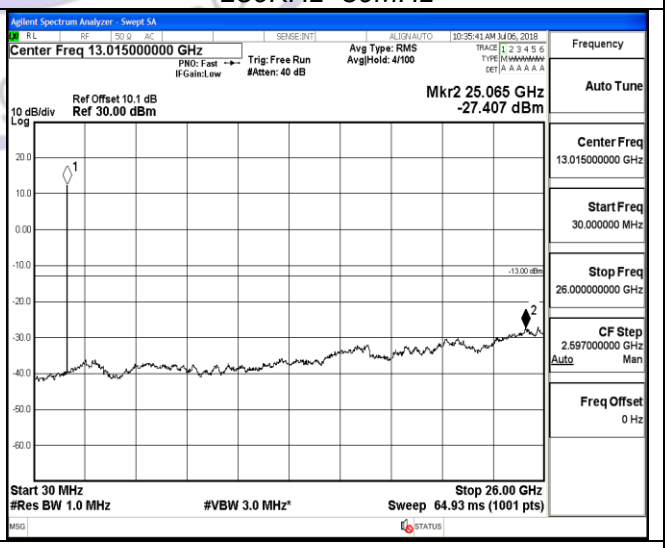
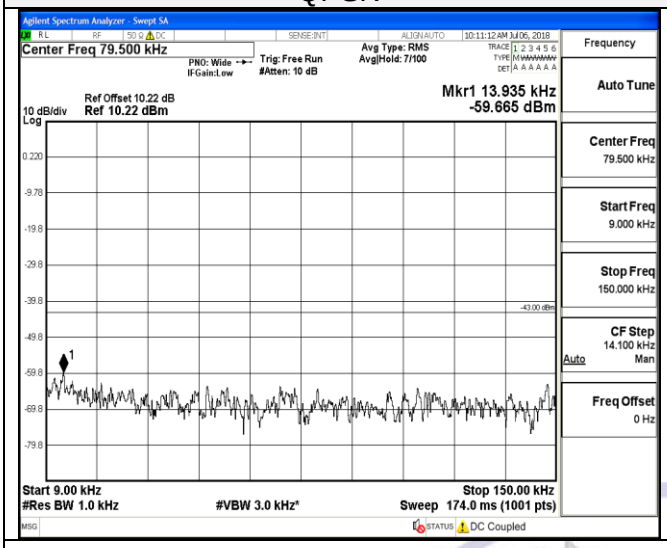
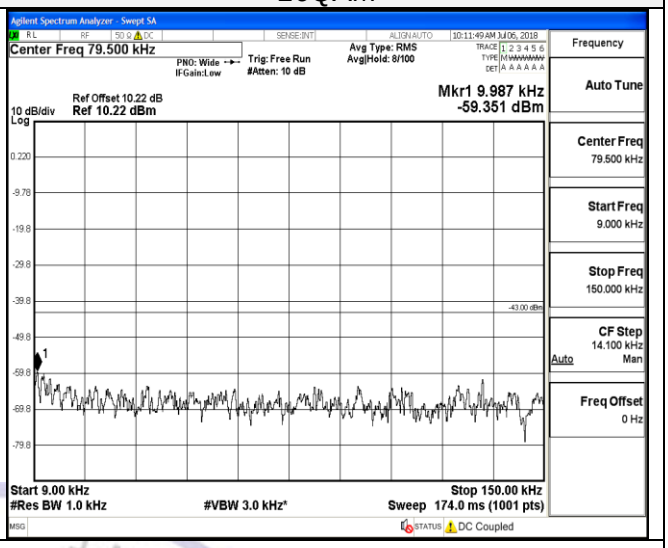
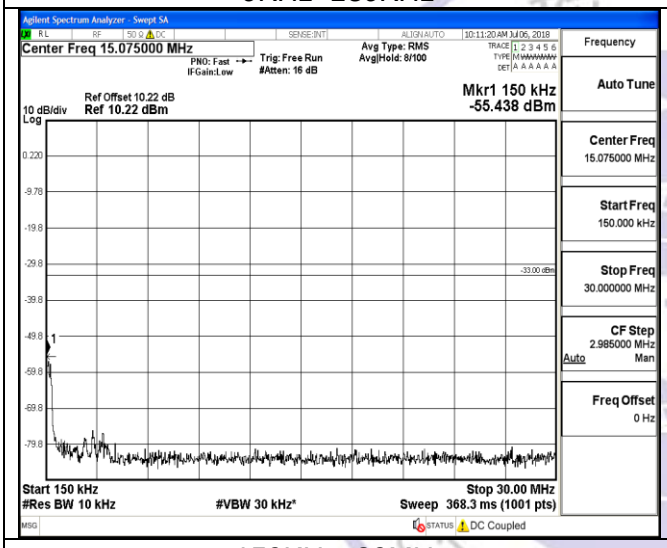
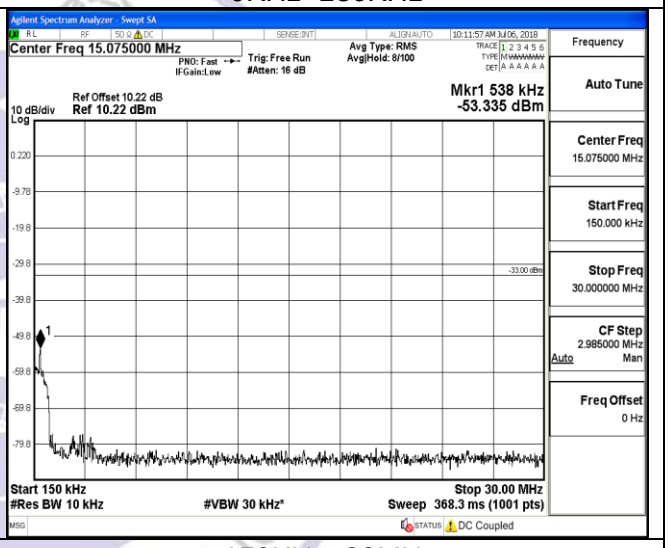
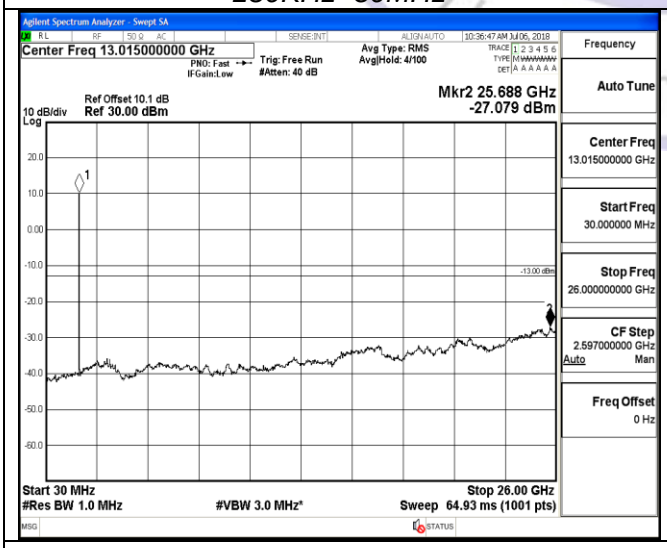
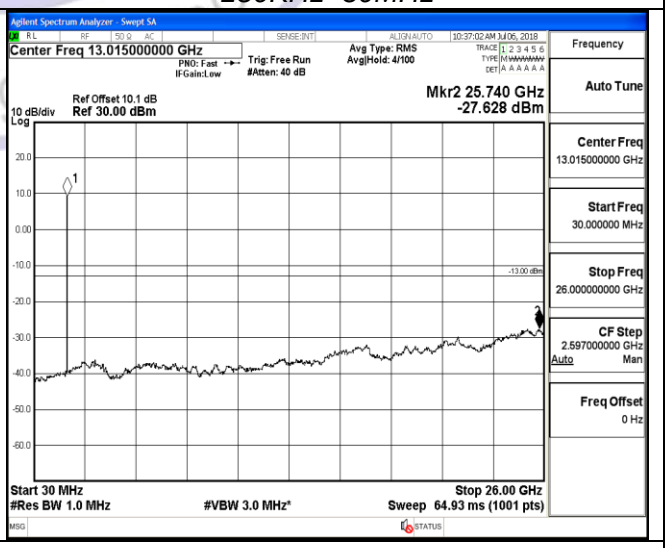
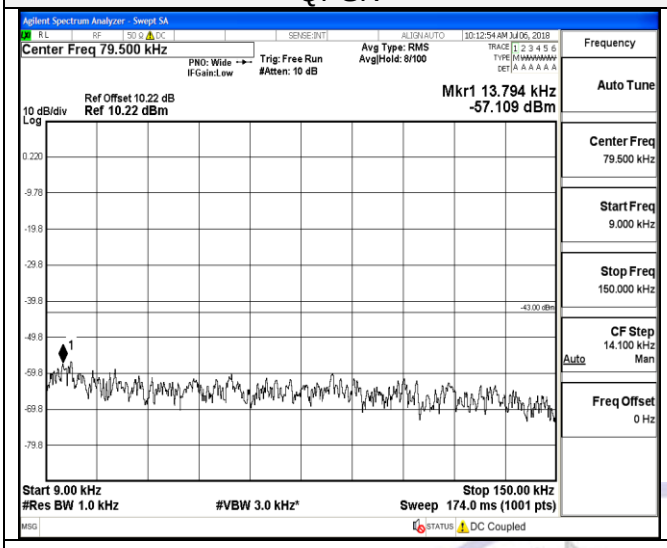
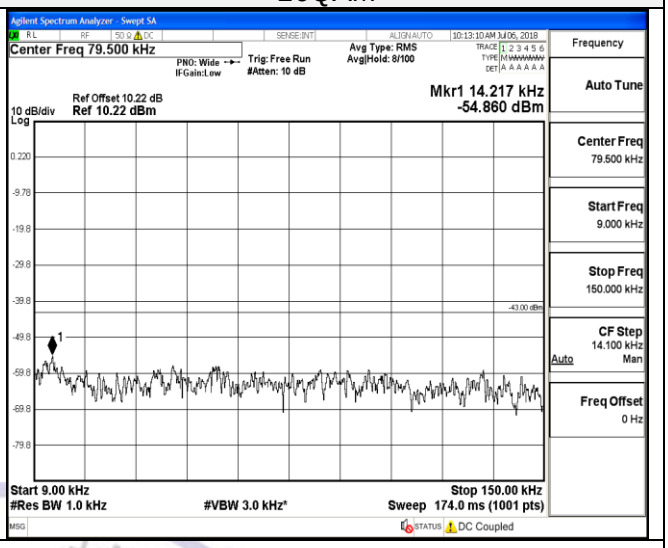
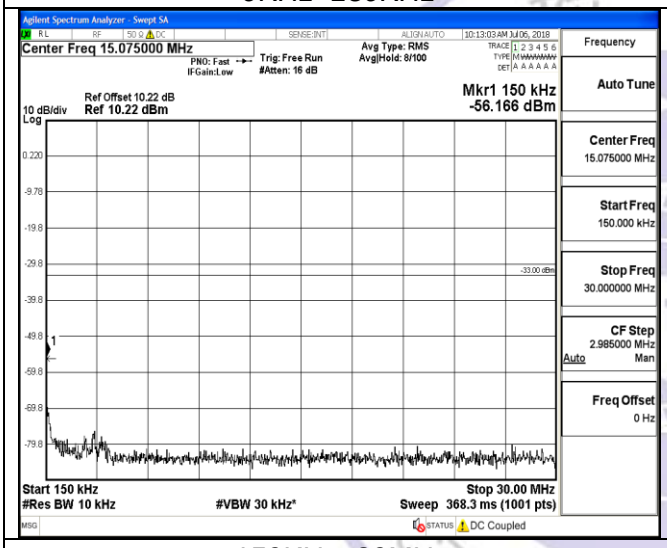
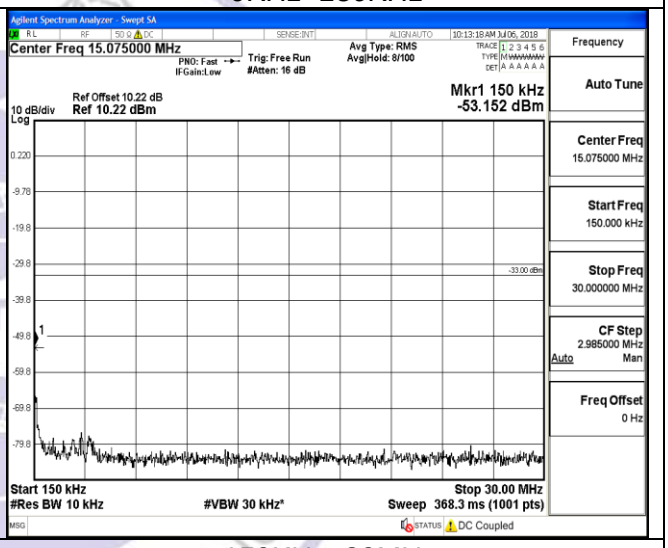
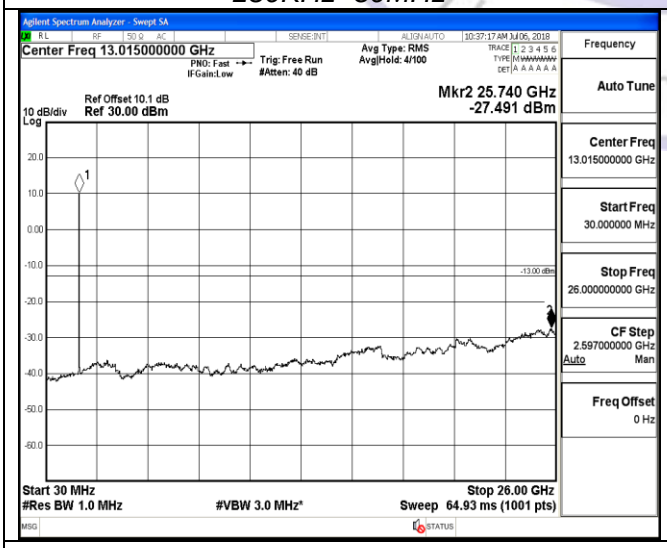
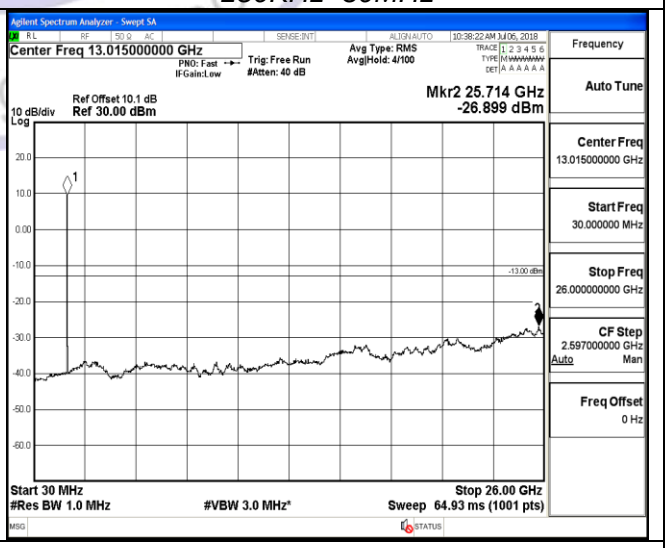
LTE FDD Band 4-20MHz Channel Bandwidth	
Low Channel	
QPSK	16QAM
	
9KHz~150KHz	9KHz~150KHz
	
150KHz~30MHz	150KHz~30MHz
	
30MHz~26.5GHz	30MHz~26.5GHz
1RB#0	1RB#0

LTE FDD Band 4-20MHz Channel Bandwidth	
Middle Channel	
QPSK	16QAM
	
9KHz~150KHz	9KHz~150KHz
	
150KHz~30MHz	150KHz~30MHz
	
30MHz~26.5GHz	30MHz~26.5GHz
1RB#0	1RB#0

LTE FDD Band 4-20MHz Channel Bandwidth	
High Channel	
QPSK	16QAM
	
9KHz~150KHz	9KHz~150KHz
	
150KHz~30MHz	150KHz~30MHz
	
30MHz~26.5GHz	30MHz~26.5GHz
1RB#0	1RB#0

Radiated Measurement:

Remark:
1. *We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 4; recorded worst case for each Channel Bandwidth of LTE FDD Band 4 @ QPSK*
2. *EIRP=P_{Mea}(dBm)-P_{cl}(dB) +G_a(dBi)*
3. *We were not recorded other points as values lower than limits.*
4. *Margin = Limit - EIRP*

LTE FDD Band 4_Channel Bandwidth 1.4MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3421.4	-35.04	4.02	3.00	12.50	-26.56	-13.00	13.56	H
5132.1	-39.83	5.11	3.00	13.38	-31.56	-13.00	18.56	H
3421.4	-32.98	4.02	3.00	12.50	-24.50	-13.00	11.50	V
5132.1	-37.25	5.11	3.00	13.38	-28.98	-13.00	15.98	V

LTE FDD Band 4_Channel Bandwidth 1.4MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-33.99	4.02	3.00	12.45	-25.56	-13.00	12.56	H
5197.5	-40.83	5.11	3.00	13.38	-32.56	-13.00	19.56	H
3465.0	-31.97	4.02	3.00	12.45	-23.54	-13.00	10.54	V
5197.5	-37.52	5.11	3.00	13.38	-29.25	-13.00	16.25	V

LTE FDD Band 4_Channel Bandwidth 1.4MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3508.6	-33.63	4.02	3.00	12.21	-25.44	-13.00	12.44	H
5262.9	-39.01	5.11	3.00	13.26	-30.86	-13.00	17.86	H
3508.6	-31.82	4.02	3.00	12.21	-23.63	-13.00	10.63	V
5262.9	-35.90	5.11	3.00	13.26	-27.75	-13.00	14.75	V

LTE FDD Band 4_Channel Bandwidth 3MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3423.0	-34.11	4.02	3.00	12.50	-25.63	-13.00	12.63	H
5134.5	-38.32	5.11	3.00	13.38	-30.05	-13.00	17.05	H
3423.0	-31.96	4.02	3.00	12.50	-23.48	-13.00	10.48	V
5134.5	-37.57	5.11	3.00	13.38	-29.30	-13.00	16.30	V

LTE FDD Band 4_Channel Bandwidth 3MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-34.57	4.02	3.00	12.45	-26.14	-13.00	13.14	H
5197.5	-38.85	5.11	3.00	13.38	-30.58	-13.00	17.58	H
3465.0	-32.06	4.02	3.00	12.45	-23.63	-13.00	10.63	V
5197.5	-35.79	5.11	3.00	13.38	-27.52	-13.00	14.52	V

LTE FDD Band 4_Channel Bandwidth 3MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3507.0	-34.06	4.02	3.00	12.21	-25.87	-13.00	12.87	H
5260.5	-38.20	5.11	3.00	13.26	-30.05	-13.00	17.05	H
3507.0	-32.74	4.02	3.00	12.21	-24.55	-13.00	11.55	V
5260.5	-35.36	5.11	3.00	13.26	-27.21	-13.00	14.21	V

LTE FDD Band 4_Channel Bandwidth 5MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3425.0	-34.53	4.02	3.00	12.50	-26.05	-13.00	13.05	H
5137.5	-38.82	5.11	3.00	13.38	-30.55	-13.00	17.55	H
3425.0	-32.52	4.02	3.00	12.50	-24.04	-13.00	11.04	V
5137.5	-35.60	5.11	3.00	13.38	-27.33	-13.00	14.33	V

LTE FDD Band 4_Channel Bandwidth 5MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-33.58	4.02	3.00	12.45	-25.15	-13.00	12.15	H
5197.5	-40.52	5.11	3.00	13.38	-32.25	-13.00	19.25	H
3465.0	-31.30	4.02	3.00	12.45	-22.87	-13.00	9.87	V
5197.5	-37.47	5.11	3.00	13.38	-29.20	-13.00	16.20	V

LTE FDD Band 4_Channel Bandwidth 5MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3505.0	-35.18	4.02	3.00	12.21	-26.99	-13.00	13.99	H
5257.5	-40.92	5.11	3.00	13.26	-32.77	-13.00	19.77	H
3505.0	-31.94	4.02	3.00	12.21	-23.75	-13.00	10.75	V
5257.5	-38.65	5.11	3.00	13.26	-30.50	-13.00	17.50	V

LTE FDD Band 4_Channel Bandwidth 10MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3430.0	-35.13	4.02	3.00	12.50	-26.65	-13.00	13.65	H
5145.0	-40.77	5.11	3.00	13.38	-32.50	-13.00	19.50	H
3430.0	-32.92	4.02	3.00	12.50	-24.44	-13.00	11.44	V
5145.0	-37.77	5.11	3.00	13.38	-29.50	-13.00	16.50	V

LTE FDD Band 4_Channel Bandwidth 10MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-34.69	4.02	3.00	12.45	-26.26	-13.00	13.26	H
5197.5	-41.07	5.11	3.00	13.38	-32.80	-13.00	19.80	H
3465.0	-32.31	4.02	3.00	12.45	-23.88	-13.00	10.88	V
5197.5	-37.67	5.11	3.00	13.38	-29.40	-13.00	16.40	V

LTE FDD Band 4_Channel Bandwidth 10MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3500.0	-34.97	4.02	3.00	12.21	-26.78	-13.00	13.78	H
5250.0	-40.50	5.11	3.00	13.26	-32.35	-13.00	19.35	H
3500.0	-31.93	4.02	3.00	12.21	-23.74	-13.00	10.74	V
5250.0	-37.20	5.11	3.00	13.26	-29.05	-13.00	16.05	V

LTE FDD Band 4_Channel Bandwidth 15MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3435.0	-34.35	4.02	3.00	12.50	-25.87	-13.00	12.87	H
5152.5	-40.77	5.11	3.00	13.38	-32.50	-13.00	19.50	H
3435.0	-31.70	4.02	3.00	12.50	-23.22	-13.00	10.22	V
5152.5	-38.77	5.11	3.00	13.38	-30.50	-13.00	17.50	V

LTE FDD Band 4_Channel Bandwidth 15MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
-31.47	-35.68	4.02	3.00	12.45	-27.25	-13.00	14.25	H
-34.31	-40.87	5.11	3.00	13.38	-32.60	-13.00	19.60	H
-29.69	-34.14	4.02	3.00	12.45	-25.71	-13.00	12.71	V
5197.5	-38.65	5.11	3.00	13.38	-30.38	-13.00	17.38	V

LTE FDD Band 4_Channel Bandwidth 15MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3495.0	-35.41	4.02	3.00	12.21	-27.22	-13.00	14.22	H
5242.5	-40.02	5.11	3.00	13.26	-31.87	-13.00	18.87	H
3495.0	-33.82	4.02	3.00	12.21	-25.63	-13.00	12.63	V
5242.5	-37.89	5.11	3.00	13.26	-29.74	-13.00	16.74	V

LTE FDD Band 4_Channel Bandwidth 20MHz_QPSK_ Low Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3440.0	-34.74	4.02	3.00	12.50	-26.26	-13.00	13.26	H
5160.0	-38.82	5.11	3.00	13.38	-30.55	-13.00	17.55	H
3440.0	-32.05	4.02	3.00	12.50	-23.57	-13.00	10.57	V
5160.0	-35.47	5.11	3.00	13.38	-27.20	-13.00	14.20	V

LTE FDD Band 4_Channel Bandwidth 20MHz_QPSK_ Middle Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-34.29	4.02	3.00	12.45	-25.86	-13.00	12.86	H
5197.5	-38.84	5.11	3.00	13.38	-30.57	-13.00	17.57	H
3465.0	-32.09	4.02	3.00	12.45	-23.66	-13.00	10.66	V
5197.5	-37.68	5.11	3.00	13.38	-29.41	-13.00	16.41	V

LTE FDD Band 4_Channel Bandwidth 20MHz_QPSK_ High Channel

Frequency (MHz)	P_{Mea} (dBm)	P_{cl} (dB)	Distance (m)	G_a Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490.0	-34.40	4.02	3.00	12.21	-26.21	-13.00	13.21	H
5235.0	-39.04	5.11	3.00	13.26	-30.89	-13.00	17.89	H
3490.0	-33.69	4.02	3.00	12.21	-25.50	-13.00	12.50	V
5235.0	-35.50	5.11	3.00	13.26	-27.35	-13.00	14.35	V

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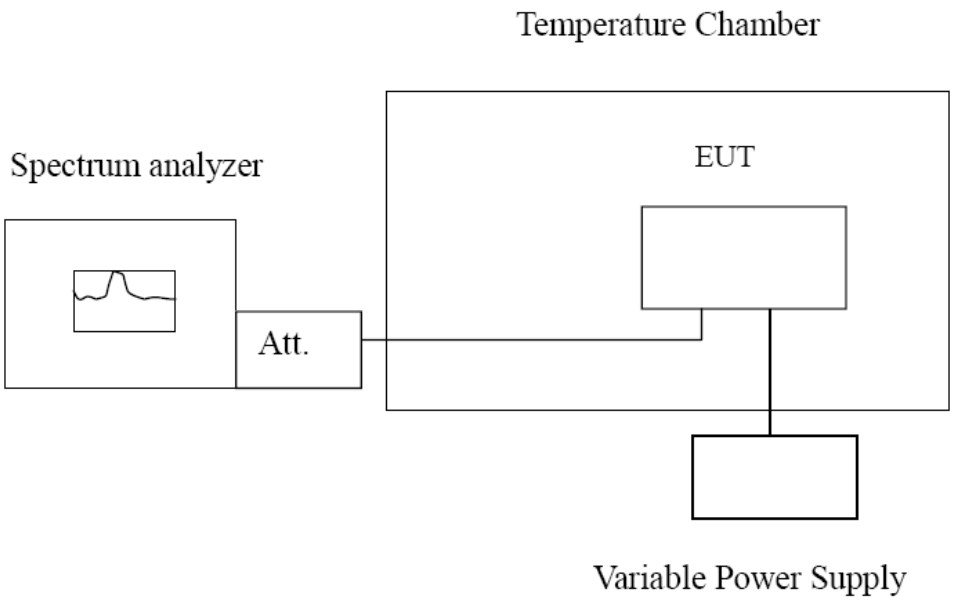
3.6. Frequency Stability under Temperature & Voltage Variations

LIMIT

According to §27.54, §2.1055 requirement, the frequency stability shall be sufficient to ensure that the fundamental emissions stay within the authorized bands of operation and should not exceed 2.5ppm.

TEST CONFIGURATION



TEST PROCEDURE

The EUT was setup according to EIA/TIA 603D

Frequency Stability under Temperature Variations:
In order to measure the carrier frequency under the condition of AFC lock, it is necessary to make measurements with the EUT in a “call mode”. This is accomplished with the use of R&S CMW500 DIGITAL RADIO COMMUNICATION TESTER.

1. Measure the carrier frequency at room temperature.
2. Subject the EUT to overnight soak at -30℃.
3. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on middle channel for LTE band 4, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
4. Repeat the above measurements at 10℃ increments from -30℃ to +50℃. Allow at least 1.5 hours at each temperature, unpowered, before making measurements.
5. Re-measure carrier frequency at room temperature with nominal voltage. Vary supply voltage from minimum voltage to maximum voltage, in 0.1Volt increments re-measuring carrier frequency at each voltage. Pause at nominal voltage for 1.5 hours unpowered, to allow any self-heating to stabilize, before continuing.
6. Subject the EUT to overnight soak at +50℃.
7. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on the centre channel, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
8. Repeat the above measurements at 10 ℃ increments from +50℃ to -30℃. Allow at least 1.5 hours at each temperature, unpowered, before making measurements
9. At all temperature levels hold the temperature to +/- 0.5℃ during the measurement procedure.

Frequency Stability under Voltage Variations:
Set chamber temperature to 20℃. Use a variable AC power supply / DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency.
Reduce the input voltage to specify extreme voltage variation (±15%) and endpoint, record the maximum frequency change.

TEST RESULTS

Remark:
1. We tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 4; recorded worst case.

LTE Band 4, 1.4MHz bandwidth (worst case of all bandwidths)

Frequency Error vs Voltage

Voltage (V)	Frequency error (Hz)		Frequency error (ppm)		Limit (ppm)
	QPSK	16QAM	QPSK	16QAM	
6.00	7.04	3.64	0.00406	0.00210	2.50
5.10	-0.14	3.53	-0.00008	0.00204	2.50
4.50	-5.54	2.09	-0.00320	0.00121	2.50

Frequency Error vs Temperature

Temperature (℃)	Frequency error (Hz)		Frequency error (ppm)		Limit (ppm)
	QPSK	16QAM	QPSK	16QAM	
-30°	-3.11	9.27	-0.00180	0.00535	2.50
-20°	0.78	3.27	0.00045	0.00189	2.50
-10°	0.45	5.20	0.00026	0.00300	2.50
0°	8.24	-1.00	0.00476	-0.00058	2.50
10°	-3.54	3.57	-0.00204	0.00206	2.50
20°	6.30	-4.39	0.00364	-0.00253	2.50
30°	3.95	-9.94	0.00228	-0.00574	2.50
40°	2.62	4.72	0.00151	0.00272	2.50
50°	-5.57	7.02	-0.00322	0.00405	2.50

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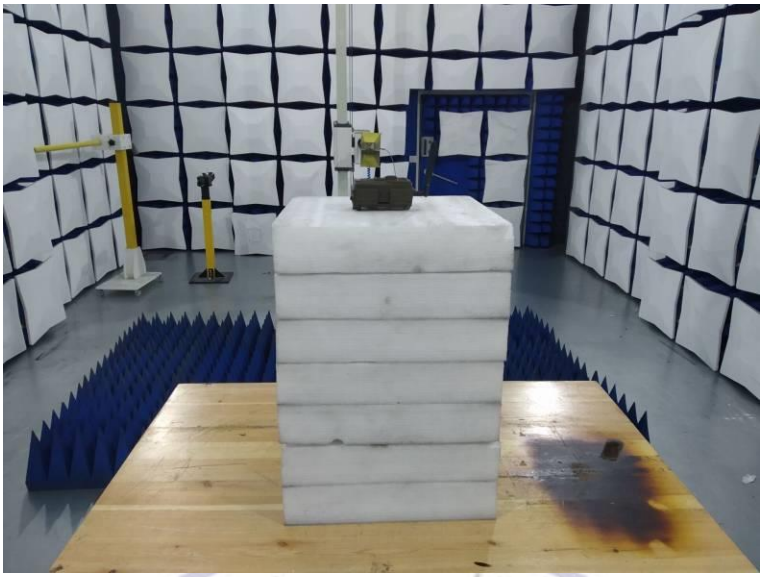
4. Test Setup Photos of the EUT



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5. Photos of the EUT

Reference to the test report No. CTL1806216041-WF01

********** End of Report **********

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华检检测